## DAP222, DAP202U

## **Common Anode Silicon Dual Switching Diodes**

These Common Anode Silicon Epitaxial Planar Dual Diodes are designed for use in ultra high speed switching applications. The DAP222 device is housed in the SC-75/SOT-416 package which is designed for low power surface mount applications, where board space is at a premium. The DAP202U device is housed in the SC-70/SOT-323 package.

#### Features

- Fast t<sub>rr</sub>
- Low C<sub>D</sub>
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

#### **MAXIMUM RATINGS** ( $T_A = 25^{\circ}C$ )

Rating	Symbol	Value	Unit
Reverse Voltage	V <sub>R</sub>	80	Vdc
Peak Reverse Voltage	V <sub>RM</sub>	80	Vdc
Forward Current	١ <sub>F</sub>	100	mAdc
Peak Forward Current	I <sub>FM</sub>	300	mAdc
Peak Forward Surge Current	I <sub>FSM</sub> (1)	2.0	Adc

#### THERMAL CHARACTERISTICS

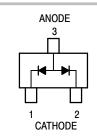
Rating	Symbol	Max	Unit
Power Dissipation	PD	150	mW
Junction Temperature	TJ	150	°C
Storage Temperature	T <sub>stg</sub>	-55 ~ +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

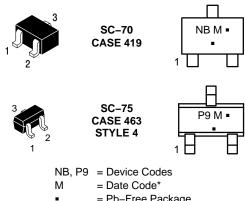


#### **ON Semiconductor®**

www.onsemi.com







= Pb–Free Package
 (Note: Microdot may be in either location)

\*Date Code orientation and/or orientation may vary depending upon manufacturing location.

#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
DAP202UG	SC–70 (Pb–Free)	3000 / Tape & Reel
DAP222G	SC–75 (Pb–Free)	3000 / Tape & Reel
DAP222T1G	SC–75 (Pb–Free)	3000 / Tape & Reel
NSVDAP222T1G	SC–75 (Pb–Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

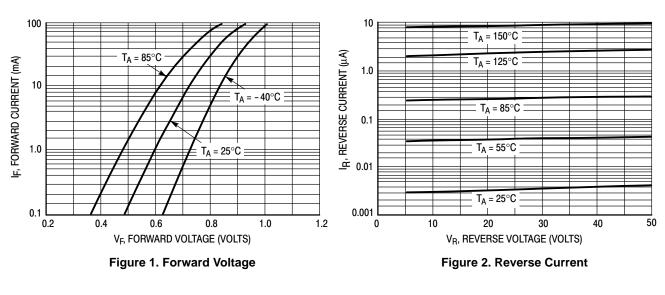
### **DAP222, DAP202U**

#### ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)

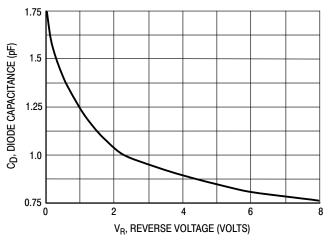
Characteristic	Symbol	Condition	Min	Max	Unit
Reverse Voltage Leakage Current	I <sub>R</sub>	V <sub>R</sub> = 70 V	-	0.1	μAdc
Forward Voltage	V <sub>F</sub>	I <sub>F</sub> = 100 mA	-	1.2	Vdc
Reverse Breakdown Voltage	V <sub>R</sub>	I <sub>R</sub> = 100 μA	80	-	Vdc
Diode Capacitance	CD	V <sub>R</sub> = 6.0 V, f = 1.0 MHz	-	3.5	pF
Reverse Recovery Time DAP222 DAP202U	t <sub>rr</sub> (2) t <sub>tt</sub> (3)	$ I_F = 5.0 \text{ mA}, \text{ V}_R = 6.0 \text{ V}, \text{ R}_L = 100 \ \Omega, \text{ I}_{rr} = 0.1 \text{ I}_R \\ I_F = 5.0 \text{ mA}, \text{ V}_R = 6.0 \text{ V}, \text{ R}_L = 50 \ \Omega, \text{ I}_{rr} = 0.1 \text{ I}_R $		4.0 10.0	ns

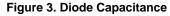
Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1.  $t = 1 \ \mu S$ 2.  $t_{rr}$  Test Circuit for DAP222 in Figure 4. 3. trr Test Circuit for DAP202U in Figure 5.



#### **TYPICAL ELECTRICAL CHARACTERISTICS**





### DAP222, DAP202U

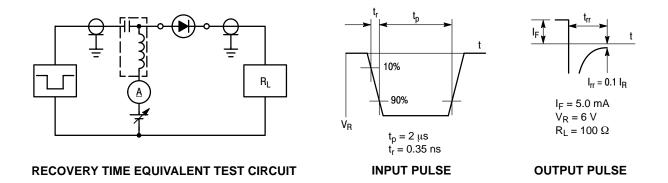


Figure 4. Reverse Recovery Time Test Circuit for the DAP222

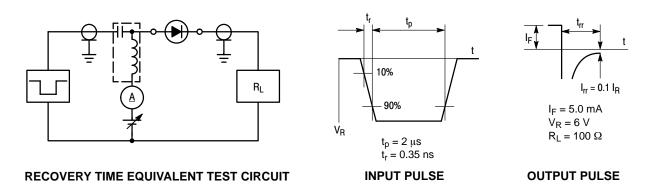
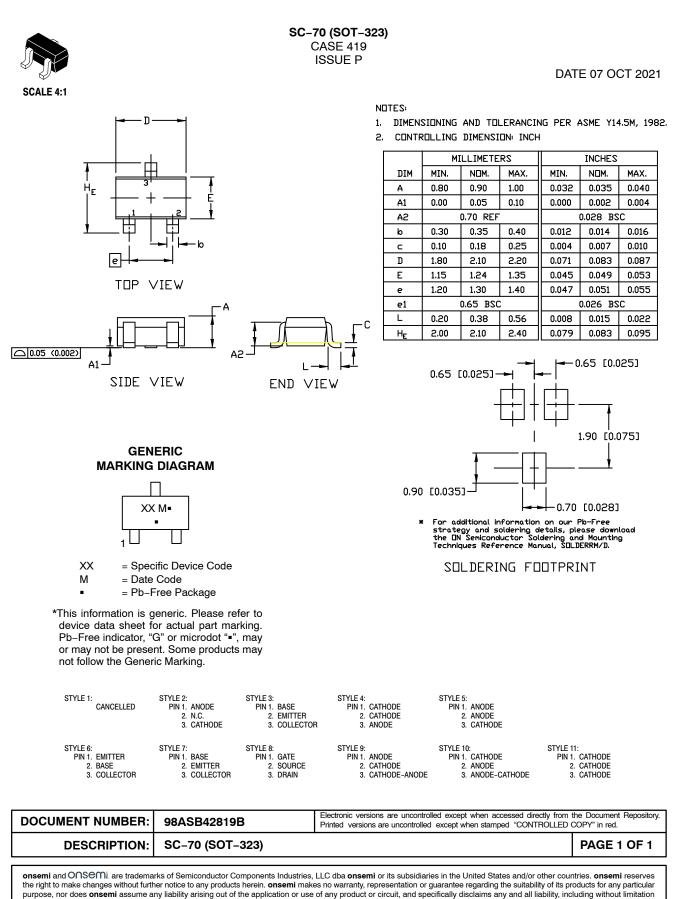


Figure 5. Reverse Recovery Time Test Circuit for the DAP202U

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\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

1.000

0.039

SCALE 10:1

mm

inches

0.508

0.020

 
 DOCUMENT NUMBER:
 98ASB15184C
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 DESCRIPTION:
 SC-75/SOT-416
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